September 1983 Revised February 1999

MM74HC175 Quad D-Type Flip-Flop With Clear

General Description

FAIRCHILD

SEMICONDUCTOR

The MM74HC175 high speed D-type flip-flop with complementary outputs utilizes advanced silicon-gate CMOS technology to achieve the high noise immunity and low power consumption of standard CMOS integrated circuits, along with the ability to drive 10 LS-TTL loads.

Information at the <u>D</u> inputs of the MM74HC175 is transferred to the Q and \overline{Q} outputs on the positive going edge of the clock pulse. Both true and complement outputs from each flip flop are externally available. All four flip-flops are controlled by a common clock and a common CLEAR. Clearing is accomplished by a negative pulse at the CLEAR input. All four Q outputs are cleared to a logical "0" and all four \overline{Q} outputs to a logical "1."

Pin Assignments for DIP, SOIC, SOP and TSSOP

13

3D

12

4D

The 74HC logic family is functionally as well as pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to $\rm V_{CC}$ and ground.

Features

- Typical propagation delay: 15 ns
- Wide operating supply voltage range: 2–6V
- Low input current: 1 μA maximum
- Low quiescent supply current: 80 µA maximum (74HC)
- High output drive current: 4 mA minimum (74HC)

Ordering Code:

Order Number	Package Number	Package Description
MM74HC175M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC175SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC175MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC175N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

30

Q

D

D

n

20

30

ā

CK CLR

CK CLF

20

10

CLOCK

GND

Connection Diagram

40

ã

15

CLR CK

CLR CK

10

Vcc

CLEAR

16

٩Ö

Q

n

10

14

Truth Table

(Each Flip-Flo Inputs			Outputs		
Clear	Q	Q			
L	Х	Х	L	Н	
н	↑	н	н	L	
н	↑	L	L	н	
Н	L	х	Q_0	\overline{Q}_0	

- H = HIGH Level (steady state)
- L = LOW Level (steady state) X = Irrelevant

↑ = Transition from LOW-to-HIGH level

 $\mathbf{Q}_0=\text{The level of }\mathbf{Q}$ before the indicated steady-state input conditions were established

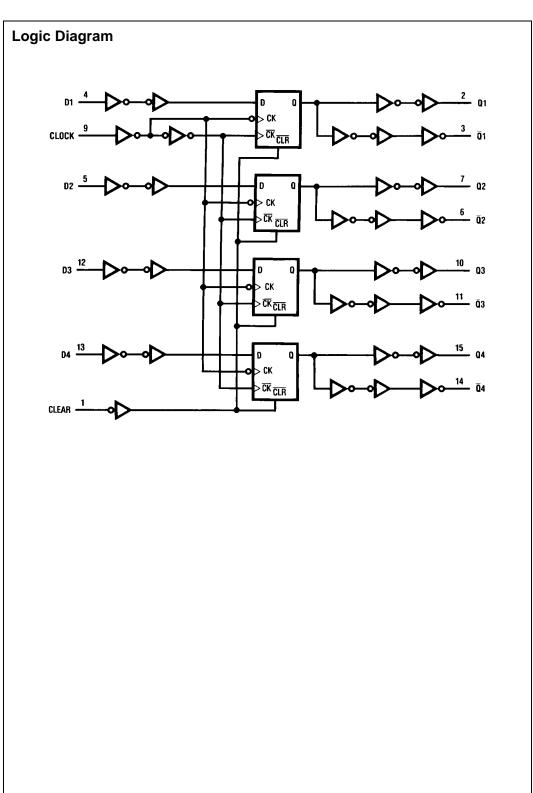
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1D

Top View

2D





Absolute Maximum Ratings(Note 1)

Recommended Operating Conditions

	U (
(Note 2)	
Supply Voltage (V _{CC})	-0.5 to +7.0V
DC Input Voltage (V _{IN})	-1.5 to $V_{CC}{+}1.5V$
DC Output Voltage (V _{OUT})	–0.5 to V_{CC} +0.5V
Clamp Diode Current (I _{IK} , I _{OK})	±20 mA
DC Output Current, per pin (I _{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I _{CC})	±50 mA
Storage Temperature Range (T _{STG})	$-65^{\circ}C$ to $+150^{\circ}C$
Power Dissipation (P _D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (TL)	
(Soldering 10 seconds)	260°C

	Min	Max	Units
Supply Voltage (V _{CC})	2	6	V
DC Input or Output Voltage			
(V _{IN} ,V _{OUT})	0	V _{CC}	V
Operating Temperature Range (T _A)	-40	+85	°C
Input Rise or Fall Times			
$(t_{r}, t_{f}) V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns
Note 1: Absolute Maximum Ratings are those	e values	beyond wh	ich dam-

MM74HC175

age to the device may occur. Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V _{cc}	$T_A = 25^{\circ}C$		$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	Units
Symbol			•cc	Тур	Guaranteed Limits			
VIH	Minimum HIGH Level		2.0V		1.5	1.5	1.5	V
	Input Voltage		4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
VIL	Maximum LOW Level		2.0V		0.5	0.5	0.5	V
	Input Voltage		4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V _{OH}	Minimum HIGH Level	$V_{IN} = V_{IH} \text{ or } V_{IL}$						
	Output Voltage	$ I_{OUT} \le 20 \ \mu A$	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$						
		$ I_{OUT} \le 4.0 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7	V
		$ I_{OUT} \le 5.2 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V
V _{OL}	Maximum LOW Level	$V_{IN} = V_{IH} \text{ or } V_{IL}$						
	Output Voltage	$ I_{OUT} \le 20 \ \mu A$	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$						
		I _{OUT} ≤ 4.0 mA	4.5V	0.2	0.26	0.33	0.4	V
		$ I_{OUT} \le 5.2 \text{ mA}$	6.0V	0.2	0.26	0.33	0.4	V
I _{IN}	Maximum Input Current	$V_{IN} = V_{CC}$ or GND	6.0V		±0.1	±1.0	±1.0	μA
I _{CC}	Maximum Quiescent	$V_{IN} = V_{CC} \text{ or } GND$	6.0V		8	80	160	μA
	Supply Current	$I_{OUT} = 0 \ \mu A$						

Note 4: For a power supply of 5V \pm 10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{O2}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

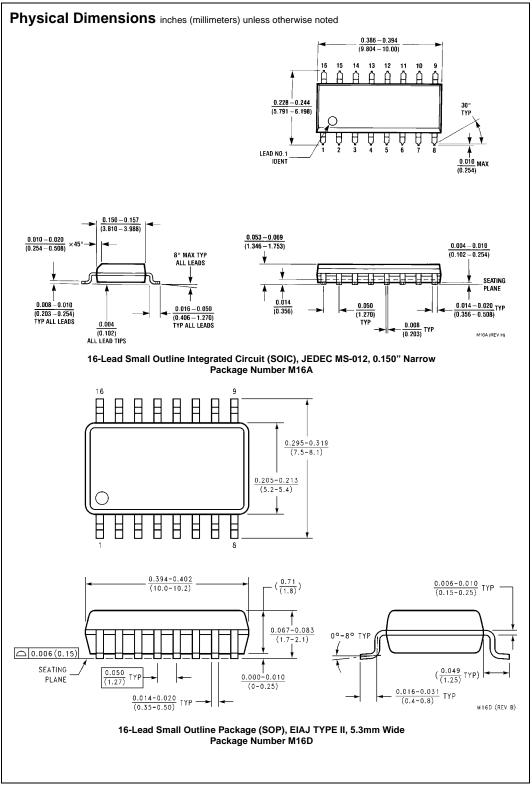
AC Electrical Characteristics

Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
f _{MAX}	Maximum Operating		60	35	MHz
	Frequency				
t _{PHL} , t _{PLH}	Maximum Propagation		15	25	ns
	Delay, Clock to Q or \overline{Q}				
t _{PHL} , t _{PLH}	Maximum Propagation		13	21	ns
	Delay, Reset to Q or \overline{Q}				
t _{REC}	Minimum Removal			20	ns
	Time, Clear to Clock				
t _S	Minimum Setup Time, Data to Clock			20	ns
t _H	Minimum Hold Time, Data from Clock			0	ns
t _W	Minimum Pulse Width, Clock or Clear		10	16	ns

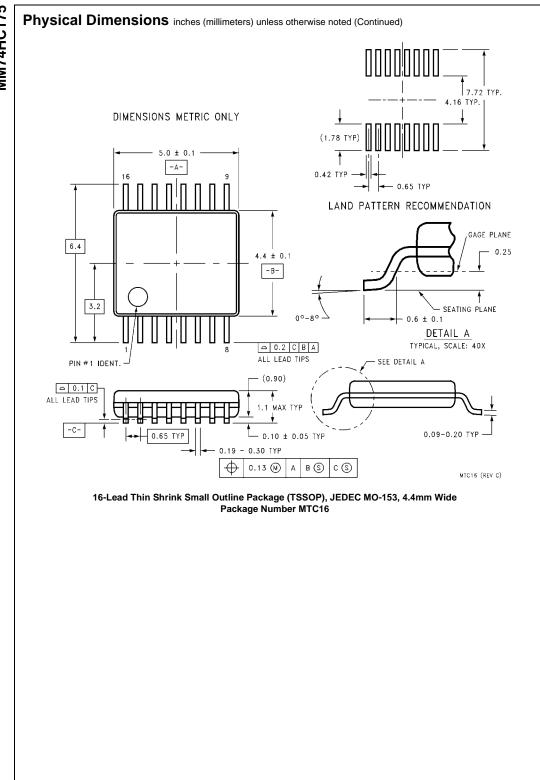
AC Electrical Characteristics

Symbol	Parameter	Conditions	Vcc	$T_A = 25^{\circ}C$		$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	Units
				Тур	Typ Guaranteed Limits			Units
f _{MAX}	Maximum Operating		2.0V	12	6	5	4	MHz
	Frequency		4.5V	60	30	24	20	MHz
			6.0V	70	35	28	24	MHz
t _{PHL} , t _{PLH}	Maximum Propagation		2.0V	80	150	190	225	ns
	Delay, Clock to Q or \overline{Q}		4.5V	15	30	38	45	ns
			6.0V	13	26	32	38	ns
t _{PHL} , t _{PLH}	Maximum Propagation		2.0V	64	125	158	186	ns
	Delay, Reset to Q or \overline{Q}		4.5V	14	25	32	37	ns
			6.0V	12	21	27	32	ns
t _{REM}	Minimum Removal Time		2.0V		100	125	150	ns
ICE IVI	Clear to Clock		4.5V		20	25	30	ns
			6.0V		17	21	25	ns
ts	Minimum Setup Time		2.0V		100	125	150	ns
0	Data to Clock		4.5V		20	25	30	ns
			6.0V		17	21	25	ns
t _H	Minimum Hold Time		2.0V		0	0	0	ns
	Data from Clock		4.5V		0	0	0	ns
			6.0V		0	0	0	ns
t _W	Minimum Pulse Width		2.0V	30	80	100	120	ns
	Clear or Clock		4.5V	9	16	20	24	ns
			6.0V	8	14	17	20	ns
t _r , t _f	Maximum Input Rise and		2.0V		1000	1000	1000	ns
	Fall Time		4.5V		500	500	500	ns
			6.0V		400	400	400	ns
t _{TLH} , t _{THL}	Maximum		2.0V	30	75	95	110	ns
	Output Rise and		4.5V	9	15	19	22	ns
	Fall Time		6.0V	8	13	16	19	ns
C _{PD}	Power Dissipation Capacitance (Note 5)	(per package)		150				pF
C _{IN}	Maximum Input Capacitance			5	10	10	10	pF

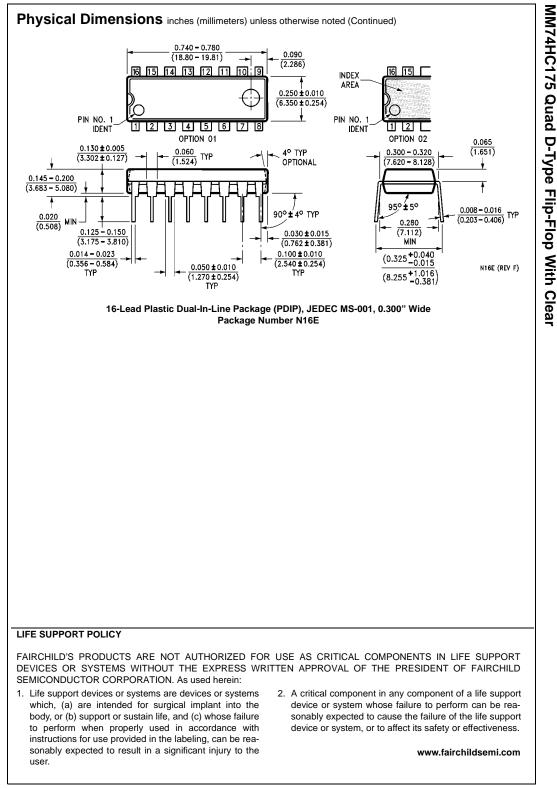
Note 5: C_{PD} determines the no load dynamic power consumption, $P_D=C_{PD}$ $V_{CC}^{2}f+I_{CC}$ V_{CC} , and the no load dynamic current consumption, $I_S=C_{PD}$ $V_{CC}^{2}f+I_{CC}$ V_{CC} , and the no load dynamic current consumption, $I_S=C_{PD}$ $V_{CC}^{2}f+I_{CC}$ V_{CC} .



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